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ON Semiconductor® FDB86563-F085

N-Channel PowerTrench[®] MOSFET

60 V, 110 A, 1.8 mΩ

Features

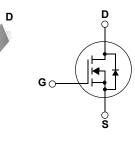
- Typical R_{DS(on)} = 1.6 mΩ at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 126 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems



TO-263 FDB SERIES



FDB86563-F085 N-Channel PowerTrench[®] MOSFET

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	110	•	
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	614	mJ	
D	Power Dissipation		333	W	
P _D	Derate Above 25°C		2.22	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
R _{0JC}	Thermal Resistance, Junction to Case		0.45	°C/W	
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

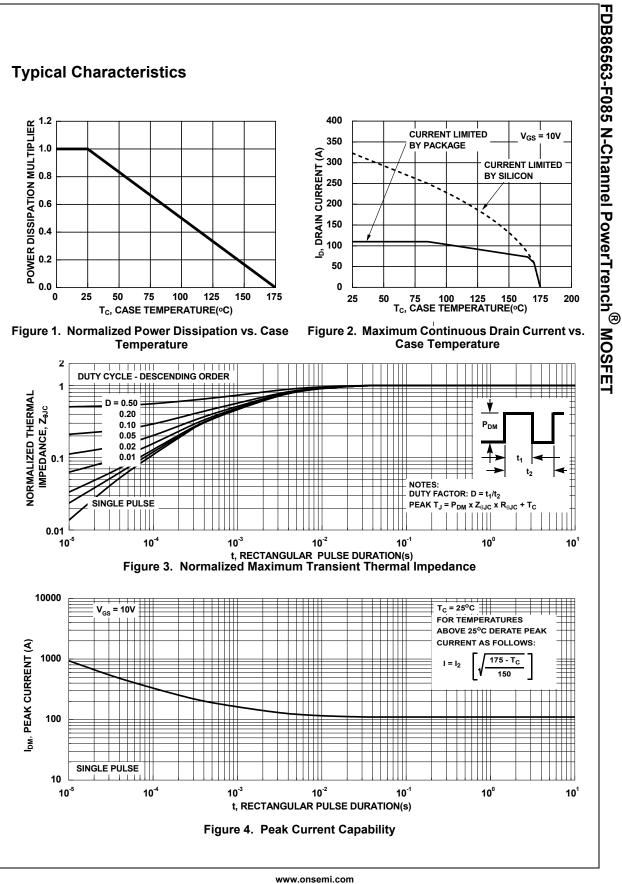
1: Current is limited by bondwire configuration.

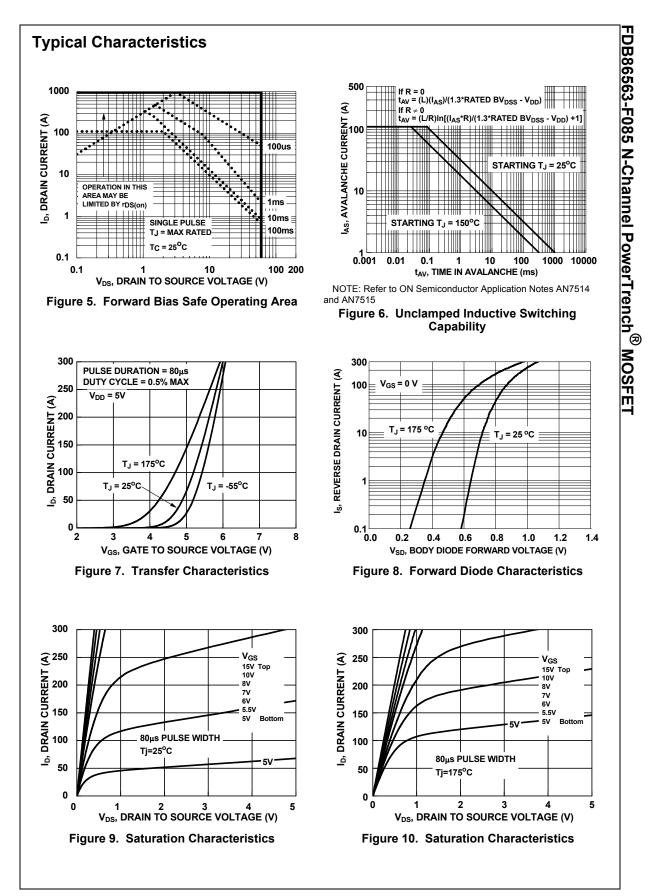
2: Starting T_J = 25°C, L = 0.3mH, I_{AS} = 64A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

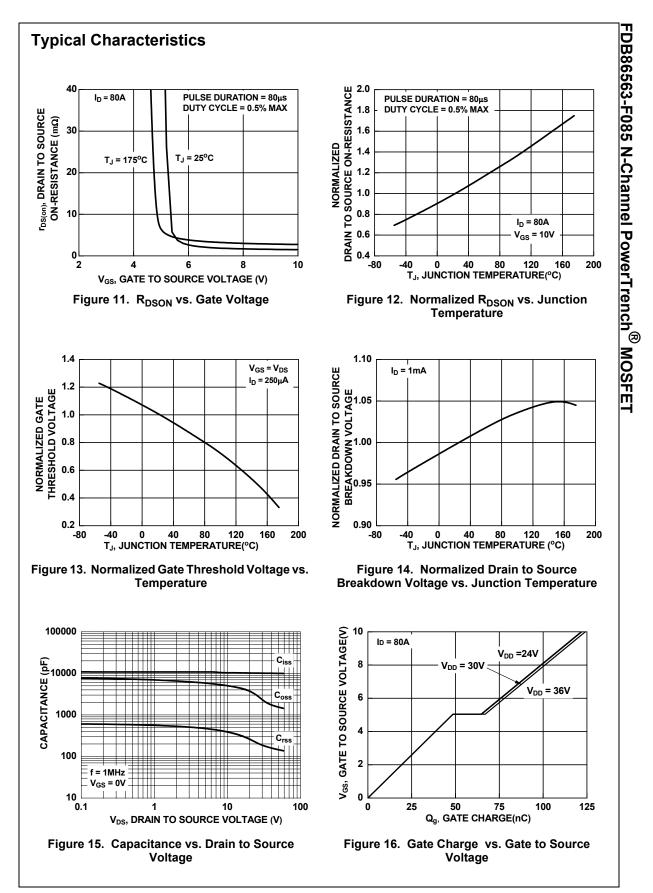
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86563	FDB86563-F085	D2-PAK(TO-263)	330mm	24mm	800units

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		60	-	-	V
	Drain-to-Source Leakage Current	V_{DS} =60V, T_{J} = 25°C		-	-	1	μA
IDSS	Drain-to-Source Leakage Current		$T_{\rm J}$ = 175°C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} ,	l _D = 250μA	2.0	2.9	4.0	V
R _{DS(on)}	Drain to Source On Resistance	I _D = 80A,	$T_J = 25^{\circ}C$	-	1.6	1.8	mΩ
		V _{GS} = 10V	$T_{\rm J}$ = 175°C (Note 4)	-	2.8	3.2	mΩ
Dynam	ic Characteristics						
C _{iss}	Input Capacitance	──V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	10100	-	pF
C _{oss}	Output Capacitance			-	2355	-	pF
C _{rss}	Reverse Transfer Capacitance			-	186	-	pF
R _g	Gate Resistance	f = 1MHz		-	4.5	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0$ to 10V $V_{DD} = 48V$		-	126	163	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2	V I _D = 80A	-	19	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	48	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	18	-	nC
	ng Characteristics					0.10	
t _{on}	Turn-On Time		-	-	-	213	ns
t _{d(on)}	Turn-On Delay	V_{DD} = 30V, I _D = 80A, V_{GS} = 10V, R _{GEN} = 6 Ω		-	28	-	ns
t _r	Rise Time			-	110	-	ns
t _{d(off)}	Turn-Off Delay			-	79	-	ns
	Fall Time Turn-Off Time			-	60	- 250	ns
				-	-	250	ns
t _{off}							
	ource Diode Characteristics						V
t _{off} Drain-S		I _{SD} =80A, V		-	-	1.25	
t _{off} Drain-S ∨ _{SD}	Source-to-Drain Diode Voltage	I _{SD} = 40A, \	/ _{GS} = 0V	-	-	1.2	V
t _{off} Drain-S		I _{SD} = 40A, \		-	- - 98 150		







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